

54FCT2245T/54FCT2245AT Octal Bidirectional Transceiver with 25Ω Series Output Resistor

General Description

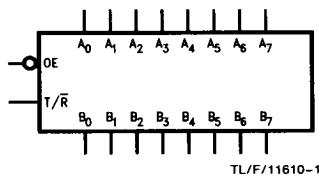
The 'FCT2245 contains eight non-inverting bidirectional buffers with TRI-STATE outputs and is intended for bus-oriented applications. The Transmit/Receive (T/R) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

The information for the 54FCT2245AT is preliminary information only.

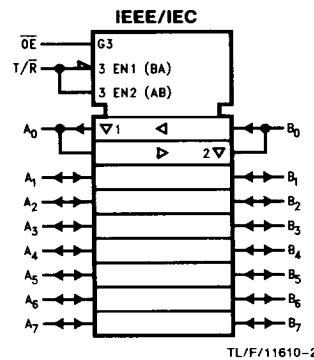
Features

- NSC54FCT2245 is pin and functionally equivalent to IDT54FCT2245
- TTL/CMOS input and output level compatible
- CMOS power levels
- 25Ω resistor limits ground bounce and transmission line ringing
- 12 mAmp I_{OL}/I_{OH}
- TRI-STATE® outputs

Logic Symbols



Pin Names	Description
OE	Output Enable Input
T/R	Transmit/Receive Input
A ₀ -A ₇	Side A TRI-STATE Inputs or TRI-STATE Outputs
B ₀ -B ₇	Side B TRI-STATE Inputs or TRI-STATE Outputs



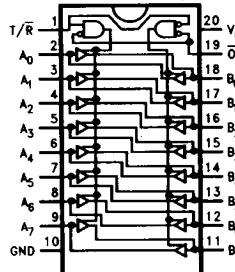
Truth Table

Inputs		Outputs
OE	T/R	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

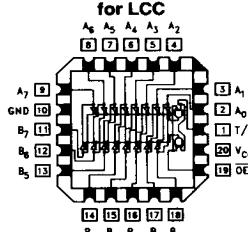
Connection Diagrams

Pin Assignment for DIP and Flatpak



TL/F/11610-3

Pin Assignment for LCC



TL/F/11610-4

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Terminal Voltage with Respect to GND (V_{TERM})
54FCT -0.5V to + 7.0V

Temperature under Bias (T_{BIAS})
54FCT -65°C to + 135°C

Storage Temperature (T_{STG})
54FCT -65°C to + 150°C

DC Output Current (I_{OUT}) 120 mA

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. Exposure to absolute maximum rating conditions for extended periods may affect reliability. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables.

Recommended Operating Conditions

Supply Voltage (V_{CC})

54FCT 4.5V to 5.5V

Input Voltage

0V to V_{CC}

Output Voltage

0V to V_{CC}

Operating Temperature (T_A)

54FCT - 55°C to + 125°C

Junction Temperature (T_J)

CDIP 175°C

DC Characteristics for 'FCT Family Devices

Symbol	Parameter	54FCT		Units	Conditions	
		Min	Max			
V_{IH}	Minimum High Level Input Voltage	2.0		V		
V_{IL}	Maximum Low Level Input Voltage		0.8	V		
I_{IH}	Input High Current	5.0 5.0		μA	$V_{CC} = \text{Max}$	$V_I = V_{CC}$ $V_I = 2.7V$ (Note 2)
I_{IL}	Input Low Current	-5.0 -5.0		μA	$V_{CC} = \text{Max}$	$V_I = 0.5V$ (Note 2) $V_I = \text{GND}$
V_{IK}	Clamp Diode Voltage		-1.3	V	$V_{CC} = \text{Min}; I_N = -15 \text{ mA}$	
I_{OS}	Short Circuit Current	-60		mA	$V_{CC} = \text{Max}$ (Note 1); $V_O = \text{GND}$	
V_{OH}	Minimum High Level Output Voltage	3.0 2.4		V	$V_{CC} = \text{Min}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -300 \mu A$ $I_{OH} = -12 \text{ mA}$
V_{OL}	Maximum Low Level Output Voltage	0.2 0.5		V	$V_{CC} = \text{Min}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 300 \mu A$ $I_{OL} = 12 \text{ mA}$ (Mil)
R_{OUT}	Output Resistor Value	21	38	Ω	$V_{CC} = 4.5V, I_{OL} = 12 \text{ mA}, 25^\circ C$	

DC Characteristics for 'FCT Family Devices (Continued)

Symbol	Parameter	54FCT		Units	Conditions	
		Min	Max			
I _{CC}	Maximum Quiescent Supply Current		1.5	mA	V _{CC} = Max V _{IN} ≥ V _{HC} , V _{IN} ≤ 0.2V f _i = 0	
ΔI _{CC}	Quiescent Supply Current; TTL Inputs HIGH		2.0	mA	V _{CC} = Max V _{IN} = 3.4V (Note 3)	
I _{CCD}	Dynamic Power Supply Current (Note 4)		0.25	mA/MHz	V _{CC} = Max Outputs Open T/R = OĒ = GND One Input Toggling 50% Duty Cycle	V _{IN} ≥ V _{HC} V _{IN} ≤ 0.2V
I _C	Total Power Supply Current (Note 6)		4.5	mA	V _{CC} = Max Outputs Open T/R = OĒ = GND f _i = 10 MHz One Bit Toggling 50% Duty Cycle	V _{IN} ≥ V _{HC} V _{IN} ≤ 0.2V
			5.0		(Note 5) V _{CC} = Max Outputs Open T/R = OĒ = GND f _i = 2.5 MHz Eight Bits Toggling 50% Duty Cycle	V _{IN} = 3.4V V _{IN} = GND
			10.0			V _{IN} ≥ V _{HC} V _{IN} ≤ 0.2V
			14.5			V _{IN} = 3.4V V _{IN} = GND

Note 1: Maximum test duration not to exceed one second, not more than one output shorted at one time.

Note 2: This parameter guaranteed but not tested.

Note 3: Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.

Note 4: This parameter is not directly testable, but is derived for use in Total Power Supply calculations.

Note 5: Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

Note 6: I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}

$$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_i = Input Frequency

N_i = Number of Inputs at f_i

All currents are millamps and all frequencies are in megahertz.

Note 7: For 54FCT, I_{CCD} = 0.40 mA/MHz.

Refer to applicable standard military drawing or NSC Table I for test conditions and I_C/I_{CC} limits.

AC Electrical Characteristics

Symbol	Parameter	54FCT2245T	54FCT2245AT	Units		
		$R_L = 500\Omega$	$R_L = 500\Omega$			
		CL = 50 pF	CL = 50 pF			
		Min (Note)	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay A to B, B to A	1.5	7.5	1.5	4.9	ns
t _{PZH} t _{PZL}	Output Enable Time OE to A or B	1.5	10.0	1.5	6.5	ns
t _{PHZ} t _{PHL}	Output Disable Time OE to A or B	1.5	10.0	1.5	6.5	ns
t _{PZH} t _{PZL}	Output Enable Time T/R to A or B	1.5	10.0	1.5	6.5	ns
t _{PHZ} t _{PZL}	Output Enable Time T/R to A or B	1.5	10.0	1.5	6.5	ns

Note: Minimum limits guaranteed but not tested on propagation delays.

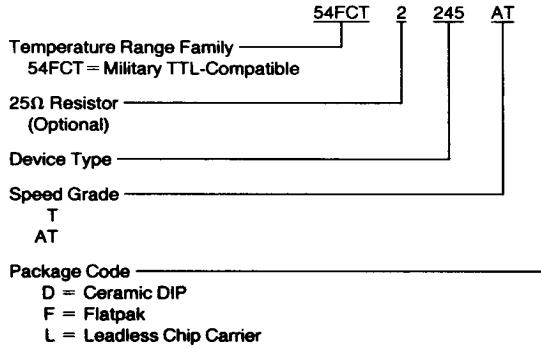
Capacitance $T_A = +25^\circ C, f = 1.0 \text{ MHz}$

Symbol	Parameter (Note)	Max	Units	Conditions
C _{IN}	Input Capacitance	12	pF	V _{IN} = 0V
C _{OUT}	Output Capacitance	12	pF	V _{OUT} = 0V

Note: This parameter is measured at characterization but not tested.

Ordering Information

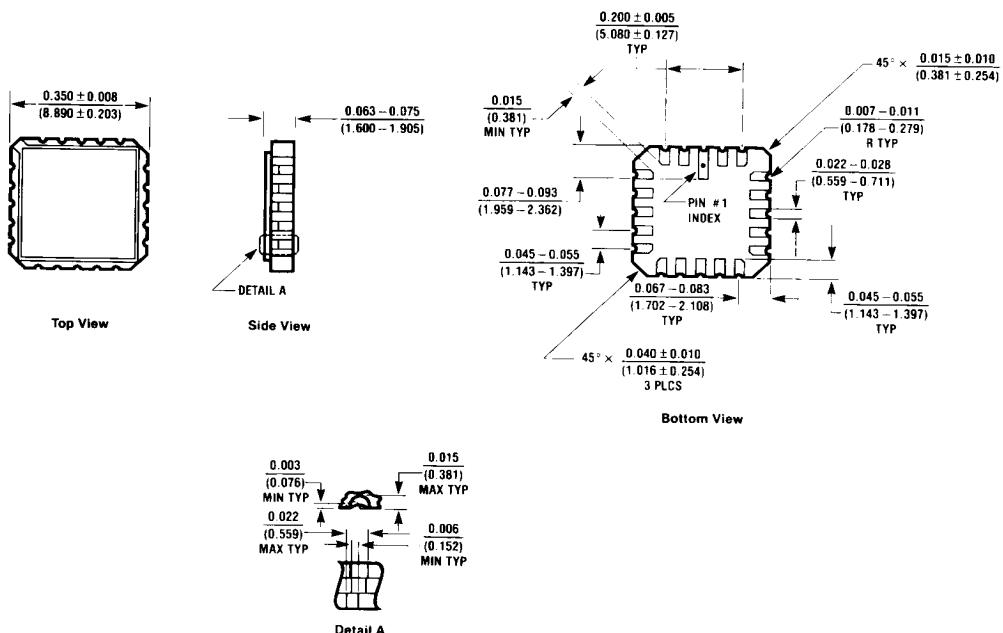
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



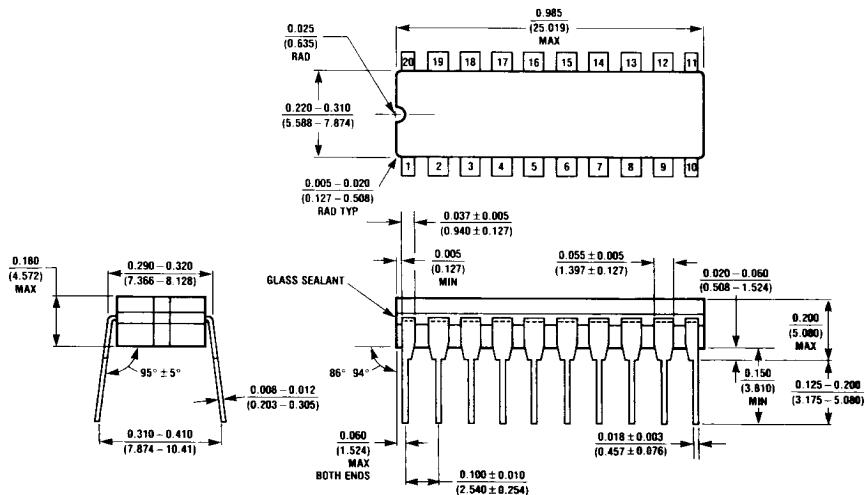
Special Variations
QB = Military grade device
with environmental and
burn-in processing
shipped in tubes

Temperature Range
M = Military (-55°C to
+125°C)

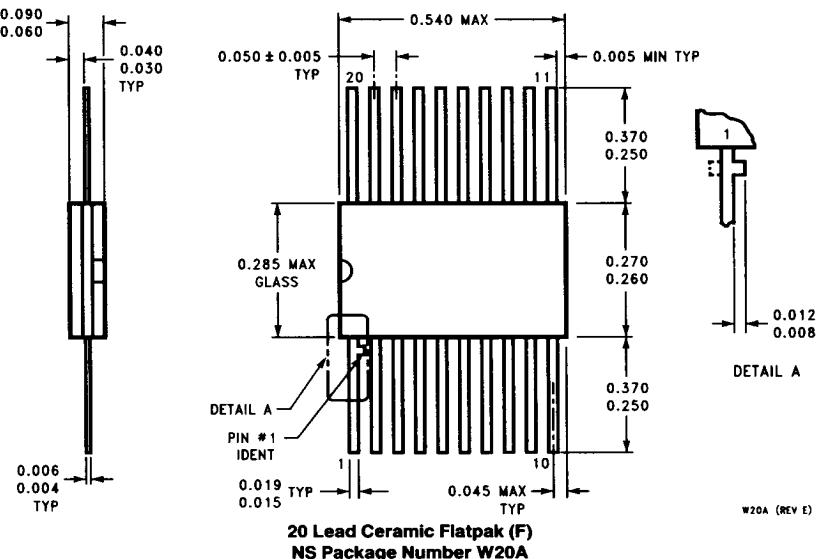
Physical Dimensions inches (millimeters)



**20-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A**



**20 Lead Ceramic Dual-In-Line Package (D)
NS Package Number J20A**



LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

038619 ✓ - R

	National Semiconductor Corporation 2900 Semiconductor Drive P.O. Box 58090 Santa Clara, CA 95052-8090 Tel: (800) 272-9895 TWX: (910) 339-9240	National Semiconductor Industriestrasse 10 D-6800 Fuerstenfeldbruck Germany Tel: (0 81-41) 103-0 Fax: (0 81-41) 10-35-06	National Semiconductor Japan Ltd. Senseido Bldg. 5F 1-15-3 Nishi Shinjuku Shinjuku-Ku Tokyo 160 Tel: 3-3298-7001 Fax: 3-3299-7000	National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 737-1600 Telex: 51292 NSHKL Fax: (852) 736-9960	National Semiconductors Do Brdo Ltda. Av. Brig. Faria Lima, 1409 6 Ander Cep-01451, Paulista, Sao Paulo, SP, Brazil Tel: (55-11) 212-5065 Telex: 391-13931 NSBR BR Fax: (55-11) 212-1181	National Semiconductor (Australia) Pty. Ltd. 16 Business Park Dr. Notting Hill, VIC 3168 Australia Tel: (0 3) 556-9999 Fax: (0 3) 556-9998
---	--	---	---	--	---	---

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.